

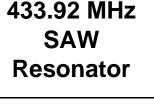
- Ideal for 433.92 MHz Transmitters
- Very Low Series Resistance
- Quartz Stability
- Rugged, Hermetic, Low-Profile TO39 Case
- Complies with Directive 2002/95/EC (RoHS)



The RO3101 is a true one-port, surface-acoustic-wave (SAW) resonator in a low-profile TO39 case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 433.92 MHz. The RO3101 is designed specifically for remote-control and wireless security transmitters operating in Europe under ETSI I-ETS 300 220 and in Germany under FTZ 17 TR 2100.

#### **Absolute Maximum Ratings**

Rating	Value	Units
CW RF Power Dissipation	+0	dBm
DC Voltage Between Any Two Pins	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds / 5 cycles Max.)	260	°C



**RO3101** 



## **Electrical Characteristics**

Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Center Frequency (+25 °C)	Absolute Frequency	f <sub>C</sub>	0.0.4.5	433.845		433.995	MHz
	Tolerance from 433.920 MHz	$\Delta f_C$	2, 3, 4, 5			±75	kHz
Insertion Loss		IL	2, 5, 6		1.5	2.0	dB
Quality Factor	Unloaded Q	QU	5, 6, 7		7400		
	50 $\Omega$ Loaded Q	QL			900		
Temperature Stability	Turnover Temperature	Т <sub>О</sub>		10	25	40	°C
	Turnover Frequency	f <sub>O</sub>	6, 7, 8		f <sub>c</sub> + 2.7		kHz
	Frequency Temperature Coefficient	FTC	-		0.037		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	f <sub>A</sub>	1		≤10		ppm/yr
DC Insulation Resistance between Any Two Pins			5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>			13.7		Ω
	Motional Inductance	L <sub>M</sub>	5, 7, 9		37.1		μH
	Motional Capacitance	CM			3.6		fF
	Pin 1 to Pin 2 Static Capacitance	CO	5, 6, 9		2.7		pF
	Transducer Static Capacitance	CP	5, 6, 7, 9		2.5		pF
Test Fixture Shunt Inductance		L <sub>TEST</sub>	2, 7		50.0		nH
Lid Symbolization (in Addition to Lot and/or Date Codes)		RFM RO3101					

CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.

Notes:

- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing significantly in subsequent years.
  The center frequency, f<sub>C</sub>, is measured at the minimum insertion loss point, the center frequency is a second secon
- 2. The center frequency,  $f_C$ , is measured at the minimum insertion loss point,  $IL_{MIN}$ , with the resonator in the 50  $\Omega$  test system (VSWR  $\leq$  1.2:1). The shunt inductance,  $L_{TEST}$ , is tuned for parallel resonance with  $C_O$  at  $f_C$ . Typically,  $f_{OSCILLATOR}$  or  $f_{TRANSMITTER}$  is less than the resonator  $f_C$ .
- 3. One or more of the following United States patents apply: 4,454,488 and 4,616,197 and others pending.
- Typically, equipment designs utilizing this device require emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- 5. Unless noted otherwise, case temperature  $T_C = +25^{\circ}C \pm 2^{\circ}C$ .
- 6. The design, manufacturing process, and specifications of this device are

subject to change without notice.

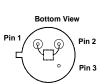
- Derived mathematically from one or more of the following directly measured parameters: f<sub>C</sub>, IL, 3 dB bandwidth, f<sub>C</sub> versus T<sub>C</sub>, and C<sub>O</sub>.
- Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover) frequency, f<sub>O</sub>. The nominal frequency at any case temperature, T<sub>C</sub>, may be calculated from: f = f<sub>O</sub> [1 FTC (T<sub>O</sub> -T<sub>C</sub>)<sup>2</sup>]. Typically, oscillator T<sub>O</sub> is 20°C less than the specified resonator T<sub>O</sub>.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C<sub>O</sub> is the static (nonmotional) capacitance between pin1 and pin 2 measured at low frequency (10 MHz) with a capacitance meter. The measurement includes case parasitic capacitance with a floating case. For usual grounded case applications (with ground connected to either pin 1 or pin 2 and to the case), add approximately 0.25 pF to C<sub>O</sub>.

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### **Electrical Connections**

This one-port, two-terminal SAW resonator is bidirectional. The terminals are interchangeable with the exception of circuit board layout.

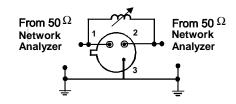
Pin	Connection	
1	Terminal 1	
2	Terminal 2	
3	Case Ground	



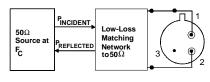
# **Typical Test Circuit**

The test circuit inductor,  $L_{\text{TEST}}$  is tuned to resonate with the static capacitance,  $C_O$  at  $F_C.$ 

### **Electrical Test:**



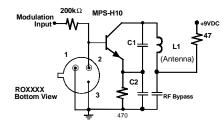
#### Power Test:



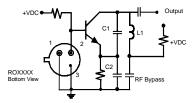
CW RF Power Dissipation = P P P REFLECTED

# **Typical Application Circuits**

#### Typical Low-Power Transmitter Application:

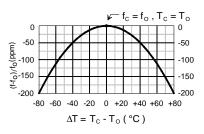


#### Typical Local Oscillator Application:



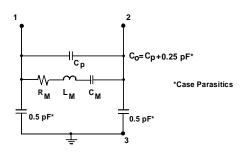
## **Temperature Characteristics**

The curve shown on the right accounts for resonator contribution only and does not include oscillator temperature characteristics.

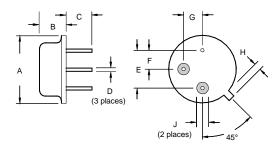


# **Equivalent LC Model**

The following equivalent LC model is valid near resonance:



#### **Case Design**



Dimensions	Millin	neters	Inches		
	Min	Max	Min	Max	
A		9.40		0.370	
В		3.18		0.125	
С	2.50	3.50	0.098	0.138	
D	0.46 Nominal		0.018 Nominal		
E	5.08 Nominal		0.200 Nominal		
F	2.54 Nominal		0.100 Nominal		
G	2.54 Nominal		0.100 Nominal		
Н		1.02		0.040	
J	1.40		0.055		

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